NSN 5961-01-158-9123

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view Online at https://aerobasegroup.com/nsn/5961-01-156-9125
Inclosure Material:
Metal
Overall Length:
1.330 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact-darlington connected
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-61
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.687 inches
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 collector to emitter voltage/static/base open and 500.0 collector to base voltage/static/emitter open and 500.0 collector to base
voltage/static/emitter open and 8.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
20.00 amperes source cutoff current and 2.50 amperes source cutoff current
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Die attach gold
Precious Material:
Gold
Test Data Document:
82577-928883 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

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